

SEMICONDUCTOR

# **MMPQ2222**

# NPN Multi-Chip General Purpose Amplifier

- This device is for use as a medium power amplifier and switch requiring collector currents up to 500mA.
- Sourced from process 19.



## Absolute Maximum Ratings \* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
I <sub>C</sub>	Collector Current - Continuous	500	mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	- 55 ~ +155	°C	

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired

### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

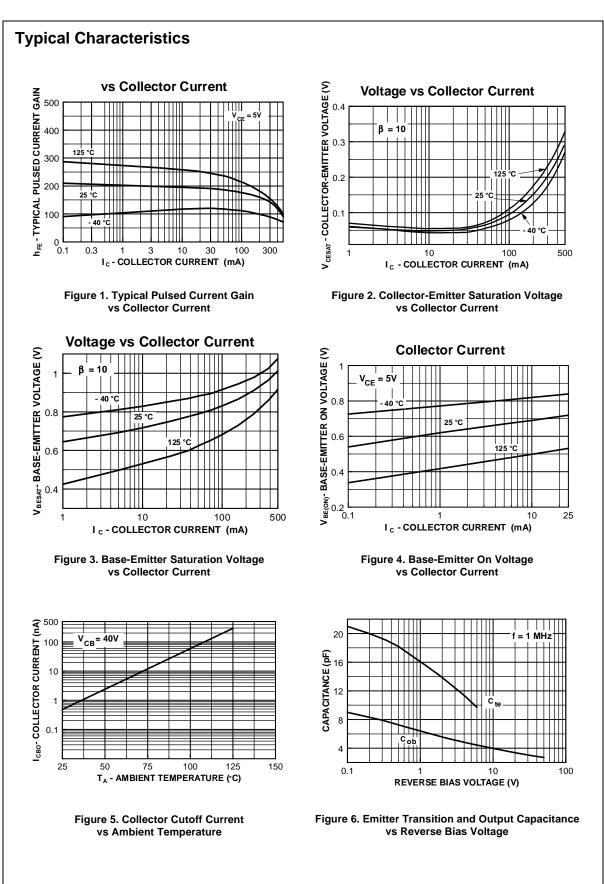
### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics	•		•	
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	30		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, \ I_{\rm E} = 0$	60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 50V, I_E = 0$		50	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB}$ = 3.0V, $I_{C}$ = 0		50	nA
On Charact	eristics *				
h <sub>FE</sub>	DC Current Gain	$I_{C} = 10mA, V_{CE} = 10V$ $I_{C} = 150mA, V_{CE} = 1.0V *$ $I_{C} = 150mA, V_{CE} = 1.0V *$	75 100 50		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage *	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA		0.4 1.6	V V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage *	$I_{C} = 150$ mA, $I_{B} = 15$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA		1.3 2.6	V V
Small Signa	I Characteristics	·			•
f <sub>T</sub>	Current GAin Bandwidth Product	$I_{C} = 20$ mA, $V_{CE} = 20$ V, f = 100MHz		300	MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 100kHz$		4.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5V, I_E = 0, f = 100 kHz$		20	pF
NF	Noise Figure	$I_{C} = 100\mu A, V_{CE} = 10V,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$		2.0	dB

\* Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2.0\%$ 

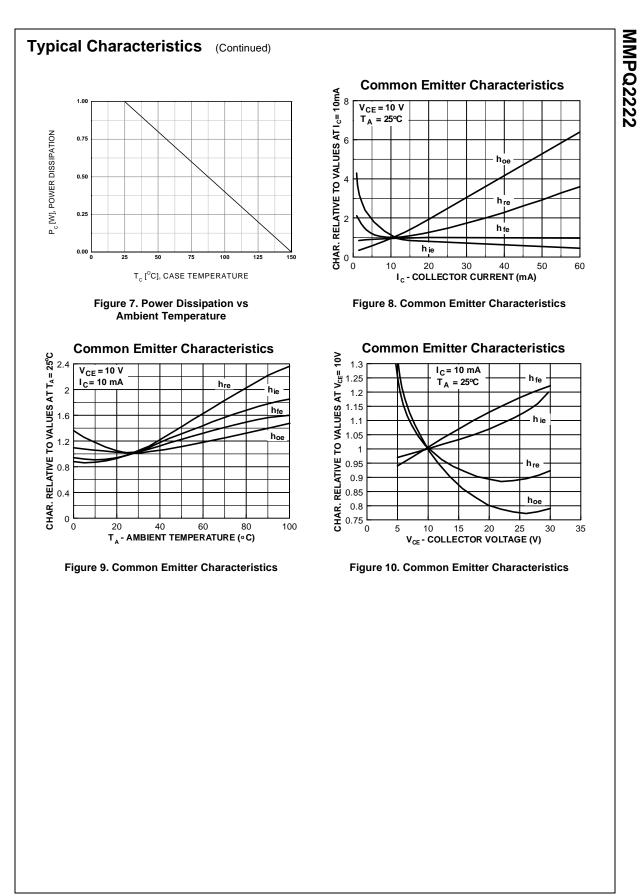
Thermal Characteristics T <sub>a</sub> =25°C unless otherwise noted         Symbol       Parameter       Max.       Units					
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	1000 8.0	mW mW/°C		
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient Effective 4 Die Each Die	125 240	°C/W °C/W		

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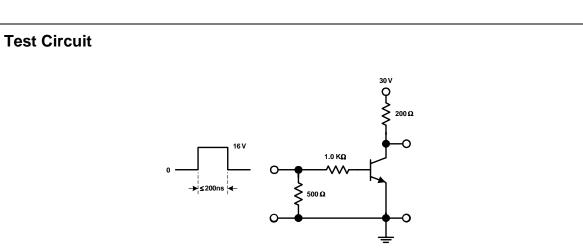
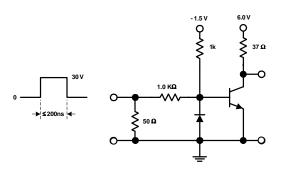
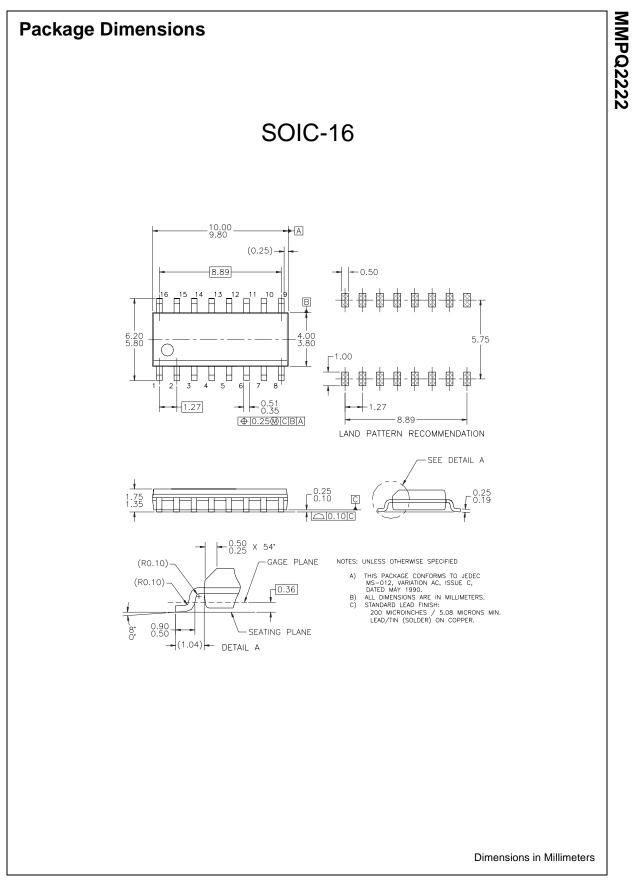


Figure 1. Saturated Turn-On Switching Time





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